# NSN 5962-00-153-2882

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## **Body Length:**

Between 0.660 inches and 0.785 inches

## **Body Width:**

Between 0.220 inches and 0.280 inches

# **Body Height:**

Between 0.140 inches and 0.180 inches

# Maximum Power Dissipation Rating:

450.0 milliwatts

#### **Operating Tempurature Range:**

-55.0/+150.0 degrees celsius

#### Storage Tempurature Range:

-65.0/+150.0 degrees celsius

#### **Features Provided:**

Hermetically sealed and monolithic and positive outputs

#### **Inclosure Material:**

## Glass and metal

Inclosure Configuration:

Dual-in-line

#### **Output Logic Form:**

Transistor-transistor logic

## Input Circuit Pattern:

6 input

## Case Outline Source And Designator:

T0-116 joint electron device engineering council

## **Terminal Surface Treatment:**

Solder

## Voltage Rating And Type Per Characteristic:

5.5 volts power source

## **Time Rating Per Chacteristic:**

50.00 nanoseconds propagation delay time, low to high level output and 50.00 nanoseconds propagation delay time, high to low level output

## Memory Device Type:

First-in first-out

#### **Test Data Document:**

07148-80707 drawing (this is the basic governing drawing, such as a contractor drawing, original equipment manufacturer drawing, etc.;

excludes any specification, standard or other document that may be referenced in a basic governing drawing)

# Terminal Type And Quantity:

14 printed circuit

# Shelf Life:

N/a

#### Unit Of Measure:

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Demilitarization:

Yes - demil/mli

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